# NSN 5962-01-296-3070

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# **Overall Height:**

0.345 inches

# Body Length:

1.290 inches

# Body Width:

0.600 inches

## **Body Height:**

0.205 inches

## **Maximum Power Dissipation Rating:**

245.0 milliwatts

## **Operating Tempurature Range:**

-55.0/+125.0 degrees celsius

# Storage Tempurature Range:

-65.0/+150.0 degrees celsius

### **End Application:**

5820-01-223-8487 converter, signal da

### **Features Provided:**

Ultraviolet erasable and programmable and 3-state output and high impedance and low power

#### Inclosure Material:

Ceramic

## Inclosure Configuration:

Dual-in-line

#### **Output Logic Form:**

N-type metal oxide-semiconductor logic

#### Input Circuit Pattern:

11 input

## **Terminal Surface Treatment:**

Solder

## Voltage Rating And Type Per Characteristic:

-0.3 volts power source and 15.0 volts power source

#### Memory Device Type:

Rom

## Test Data Document:

96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).

## Terminal Type And Quantity:

24 printed circuit

## Shelf Life:

N/a

## Unit Of Measure:

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## Demilitarization:

Yes - demil/mli

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